
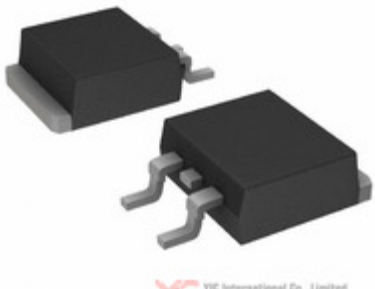
	<p><b>SUD50N03-12P-E3</b></p>
	<p><b>Hersteller-Teilenummer:</b> SUD50N03-12P-E3</p> <p><b>Hersteller / Marke:</b> Vishay / Siliconix</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 30V TO252</p> <p><b>Datenblätter:</b>  <a href="#">SUD50N03-12P-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 15620 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	SUD50N03-12P-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V TO252
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	15620 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	6.5W (Ta), 46.8W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	-
Rds On (Max) @ Id, Vgs	12 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	42nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1600pF @ 25V
Verpackung	Tape & Reel (TR)



















































SUD50N03-12P-E3 ist neu im Original, Suche SUD50N03-12P-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD50N03-12P-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SUD50N03-12P-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SUD50N03-12P-GE3</b> Vishay / Siliconix MOSFET N-CH 30V 16.8A TO252</p>	 <p><b>SUD50N03-16P-E3</b> Vishay / Siliconix MOSFET N-CH 30V TO252</p>	 <p><b>SUD50N03-11-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 50A TO252</p>	 <p><b>SUD50N03-11-T4-E3</b> VIS VIS TO-252</p>
 <p><b>SUD50N03-11-E3-PBF</b> VISHAY VISHAY TO252</p>	 <p><b>SUD50N03-11-E3</b> Vishay / Siliconix MOSFET N-CH 30V 50A TO252</p>	 <p><b>SUD50N03-16P</b> VISHAY SUD50N03-16P VISHAY</p>	 <p><b>SUD50N03-12P-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 16.8A TO252</p>

### heiße Teile

Mehr

 SUD50N025-09BP-E3	 SUD50N03	 SUD50N03-06	 SUD50N03-06P	 SUD50N03-06P-E3
 SUD50N03-06P-E3	 SUD50N03-07	 SUD50N03-07AP	 SUD50N03-07P	 SUD50N03-09
 SUD50N03-09P	 SUD50N03-09P-E3	 SUD50N03-09P-E3	 SUD50N03-10	 SUD50N03-10-T4
 SUD50N03-10AP	 SUD50N03-10BP	 SUD50N03-10BP-T4	 SUD50N03-10CP	 SUD50N03-10P
 SUD50N03-11	 SUD50N03-11-E3	 SUD50N03-11-E3	 SUD50N03-12P	 SUD50N03-12P-E3
 SUD50N03-16P	 SUD50N03-7M3P	 SUD50N03A	 SUD50N04-05L	 SUD50N04-05L-E3
 SUD50N04-05L-E3	 SUD50N04-06H	 SUD50N04-06P	 SUD50N04-07	 SUD50N04-07-T4-GE3
 SUD50N04-07L	 SUD50N04-07L-E3	 SUD50N04-09H	 SUD50N04-09H-E3	 SUD50N04-09H-E3
 SUD50N04-09L-E3	 SUD50N04-10P-E3	 SUD50N04-13P	 SUD50N04-13P-E3	 SUD50N04-16P
 SUD50N04-25P	 SUD50N04-37P	 SUD50N04-37P-E3	 SUD50N04-37P-E3-4GE3	 SUD50N04-37P-T4-GE3

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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